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THIRD SERIES, VOLUME 59, NUMBER 23 *CONTENTS* 15 JUNE 1999-I

BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Anisotropic renormalization-group flow of quasiparticle weight in a two-dimensional electron system with a partially flat Fermi surface 14 823
Jun-ichiro Kishine and Kenji Yonemitsu

Dynamical nonlinear optical coefficients from the symmetrized density-matrix renormalization-group method 14 827
Swapan K. Pati, S. Ramasesha, Z. Shuai, and J. L. Brédas

Supersolid in the periodic Anderson model 14 831
Mario Cuoco and Canio Noce

Electronic structure of $1T$-TiS_2 . . . . . 14 833
Sangeeta Sharma, Tashi Nautiyal, G. S. Singh, S. Auluck, P. Blaha, and Claudia Ambrosch-Draxl

Spinless two-band model in infinite dimensions 14 837
Luis Craco

Dynamic response function and energy-loss spectrum for Li using an N-point Padé approximant 14 841
Young-Gu Jin and K. J. Chang

β function of the multichannel Kondo model 14 845
Kurt Fischer

Statistical properties of a localization-delocalization transition in one dimension 14 848
M. Steiner, Yang Chen, M. Fabrizio, and Alexander O. Gogolin

Semiconductors I: bulk

Low-temperature spectroscopic study of n-type diamond 14 852
M. Nesládek, K. Meykens, K. Haenen, L. M. Stals, T. Teraji, and S. Koizumi

Photoinduced changes of ac transport in a-As_2Se_3 films: Role of defects and band tails 14 856
Ashtosh Ganjoo, K. Shimakawa, N. Yoshida, T. Ohno, A. V. Kolobov, and Y. Ikeda

Ultrafast dephasing of continuum transitions in bulk semiconductors 14 860
S. Arlt, U. Siegner, J. Kunde, F. Morier-Genoud, and U. Keller

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Atomic structure of the Si(113)-(3×1) surface: Charge transfer within tetramers 14 864
C. C. Hwang, H. S. Kim, Y. K. Kim, J. S. Kim, C. Y. Park, K. J. Kim, T.-H. Kang, and B. Kim

Atomically perfect bismuth lines on Si(001) 14 868
K. Miki, D. R. Bowler, J. H. G. Owen, G. A. D. Briggs, and K. Sakamoto

Orbital quantization of composite fermions in antidot lattices 14 872
F. Nihey, K. Nakamura, T. Takamasu, G. Kido, T. Sakon, and M. Motokawa

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(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 59, NUMBER 23** **15 JUNE 1999-I**

Effects of surface-bond saturation on the luminescence of silicon nanocrystals 14 876
Jian-Bai Xia and K. W. Cheah
Electron-electron interactions between orbital pairs in quantum dots 14 880
S. Nagaraja, L. R. C. Fonseca, and J. P. Leburton
Self-consistent approach to Coulombic effects on the quantum magnetotransport in a nondegenerate two-dimensional electron liquid 14 884
Yu. P. Monarkha, E. Teske, and P. Wyder
Interlayer coherence in $\nu=1$ and $\nu=2$ bilayer quantum Hall states 14 888
A. Sawada, Z. F. Ezawa, H. Ohno, Y. Horikoshi, A. Urayama, Y. Ohno, S. Kishimoto, F. Matsukura, and N. Kumada
Raman scattering in a two-dimensional electron gas: Boltzmann equation approach 14 892
E. G. Mishchenko
Confinement effects in bulk samples derived from the Franz-Keldysh effect 14 896
H. J. Kolbe, C. Agert, W. Stolz, and G. Weiser

Surface physics, low-dimensional systems, and related topics

Surface structure determination of $CeO_2(001)$ by angle-resolved mass spectroscopy of recoiled ions 14 899
G. S. Herman
Genetic-algorithm prediction of the magic-number structure of $(C_{60})_N$ clusters with a first-principles interaction potential 14 903
You-Hua Luo, Jijun Zhao, Shutian Qiu, and Guanghou Wang
Time-resolved reflection high-energy electron diffraction study of the Ge(111)-$c(2\times8)-(1\times1)$ phase transition 14 907
Xinglin Zeng, Bo Lin, Ibrahim El-Kholy, and Hani E. Elsayed-Ali
Crystallization of a classical two-dimensional electron system: Positional and orientational orders 14 911
Satoru Muto and Hideo Aoki

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Wave-packet dynamics in slowly perturbed crystals: Gradient corrections and Berry-phase effects 14 915
Ganesh Sundaram and Qian Niu
Heat capacities (1 to 108 K) and linear thermal expansivities (1 to 300 K) of $LuH_{0.148}$ single crystals: Thermal relaxation effects and the pairing transition 14 926
C. A. Swenson
Spectral function of the two-dimensional large-$\mathcal{N}$ t-J model 14 937
Marilyn F. Bishop, Zane P. Gibbs, and T. McMullen
Collective-mode approximations in the two-dimensional large-$\mathcal{N}$ t-J model 14 969
Marilyn F. Bishop, Zane P. Gibbs, and T. McMullen
Single-particle properties of a model for coexisting charge and spin quasicritical fluctuations coupled to electrons 14 980
S. Caprara, M. Sulpizi, A. Bianconi, C. Di Castro, and M. Grilli
Correcting overbinding in local-density-approximation calculations 14 992
A. van de Walle and G. Ceder
Electronic structure and properties of pure and doped ϵ-FeSi from *ab initio* local-density theory 15 002
T. Jarlborg
Structural and electronic properties of $Si_{1-x}C_x$ alloys and the band alignment in $Si_{1-x}C_x$/Si(001) heterostructure 15 013
S. H. Ke, T. Uda, and K. Terakura

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 59, NUMBER 23** **15 JUNE 1999-I**

Ground-state properties of quasi-one-dimensional electron systems within dynamic local-field correction: Quantum Singwi-Tosi-Land-Sjölander theory 15 019
B. Tanatar and C. Bulutay
Electronic structure of the spin-Peierls system NaV_2O_5 . . . . . 15 027
Hua Wu and Qing-qi Zheng
Chemical bonding in titanium-metalloid compounds 15 033
Masataka Mizuno, Isao Tanaka, and Hirohiko Adachi
$1\,^1B_u^-$-$2\,^1A_g^+$ crossover in conjugated polymers: The phase diagram of the molecular-orbital model 15 048
Mikhail Yu. Lavrentiev and William Barford
Charge order and the metal-insulator transitions in $A_{1/2}A'_{1/2}MnO_3$ 15 056
Michel van Veenendaal and A. J. Fedro
Metal-insulator transition at 50 K in Na_2C_{60} 15 062
Y. Kubozono, Y. Takabayashi, S. Fujiki, S. Kashino, T. Kambe, Y. Iwasa, and S. Emura
Thermodynamics of CeNiSn at low temperatures and in weak magnetic fields 15 070
K. A. Kikoin, M. N. Kiselev, A. S. Mishchenko, and A. de Visser
Theoretical prediction of the peak structure in the EELS spectrum of palladium 15 085
Gregor-Martin Fehrenbach
$3s$ photoemission spectra of $3d$ transition-metal adatoms on graphite 15 093
P. Krüger, J. C. Parlebas, and A. Kotani
Doping dependence of the electronic structure of $Ba_{1-x}K_xBiO_3$ studied by x-ray-absorption spectroscopy 15 100
K. Kobayashi, T. Mizokawa, A. Ino, J. Matsuno, A. Fujimori, H. Samata, A. Mishiro, Y. Nagata, and F. M. F. de Groot
Far-field characteristics of random lasers 15 107
H. Cao, Y. G. Zhao, H. C. Ong, and R. P. H. Chang
Surface electromagnetic waves in two-dimensional photonic crystals: Effect of the position of the surface plane 15 112
F. Ramos-Mendieta and P. Halevi
X-ray investigation of the q_1 charge-density-wave modulation in substituted Ti- and Ta-$NbSe_3$ 15 121
S. Rouzière, S. Ravy, J.-P. Pouget, and R. E. Thorne
Momentum conservation law in the Car-Parrinello method 15 126
Tetsuya Morishita and Shuichi Nosé
Linear and nonlinear optical properties of the conjugated polymers PPV and MEH-PPV 15 133
S. J. Martin, D. D. C. Bradley, P. A. Lane, H. Mellor, and P. L. Burn
Numerical study of multisoliton configurations in a doped antiferromagnetic Mott insulator 15 143
Mona Berciu and Sajeev John
Slow steady transport by mixed ionic-electronic conductors: Electrochemical oxygenation of La_2CuO_{4+x} and La_2NiO_{4+x} 15 160
Wayne M. Saslow

Semiconductors I: bulk

Vacancies in SiC: Influence of Jahn-Teller distortions, spin effects, and crystal structure 15 166
A. Zywietz, J. Furthmüller, and F. Bechstedt
Predictor of p-type doping in II-VI semiconductors 15 181
D. J. Chadi
Calculation of quasiparticle energy spectrum of silicon using the correlated Hartree-Fock method 15 184
Takamitsu Ishihara, Hiroshi Yamagami, Kazuya Matsuzawa, and Hiroshi Yasuhara
Mixed-valence states in narrow-gap IV-VI semiconductors with rare-earth ions 15 190
V. K. Dugaev, V. I. Litvinov, and A. Łusakowski
Vibrational Raman and infrared studies of ordering in epitaxial $ZnSnP_2$ 15 197
A. M. Mintairov, N. A. Sadchikov, T. Sauncy, M. Holtz, G. A. Seryogin, S. A. Nikishin, and H. Temkin

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 59, NUMBER 23** **15 JUNE 1999-I**

Piezospectroscopy study of the trigonal FeIn pair center in silicon 15 208
Per Tidlund and Mats Kleverman
Mass effects on regrowth rates and activation energies of solid-phase epitaxy induced by ion beams in silicon 15 214
A. Kinomura, J. S. Williams, and K. Fujii

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Boron-induced stabilization of the Si(100)-(2×1) surface reconstruction 15 225
B. Gong, D. E. Brown, J. H. Kang, S. K. Jo, Y. M. Sun, and J. G. Ekerdt
Macroscopic and nanoscale faceting of germanium surfaces 15 230
Zheng Gai, W. S. Yang, R. G. Zhao, and T. Sakurai
Island growth and surface roughness scaling of epitaxial GaAs on Si observed by *in situ* scanning electron microscopy 15 240
Paul Finnie and Yoshikazu Homma
Model for nucleation in GaAs homoepitaxy derived from first principles 15 246
P. Kratzer, C. G. Morgan, and M. Scheffler
X-ray analysis of the short-range order in the ordered-alloy domains of epitaxial (Ga,In)P layers by diffraction anomalous fine structure of superlattice reflections 15 253
Dirk C. Meyer, Kurt Richter, Peter Paufler, and Gerald Wagner
Atomic and electronic structure of the CdTe(001) surface: LDA and *GW* calculations 15 261
S. Gundel, A. Fleszar, W. Faschinger, and W. Hanke
Electronic consequences of lateral composition modulation in semiconductor alloys 15 270
T. Mattila, L.-W. Wang, and Alex Zunger
Atomic structure of the As-rich InAs(100) $\beta2(2\times4)$ surface 15 285
M. Göthelid, Y. Garreau, M. Sauvage-Simkin, R. Pinchaux, A. Cricenti, and G. Le Lay
Spin and density longitudinal response of quantum dots in the time-dependent local-spin-density approximation 15 290
Ll. Serra, M. Barranco, A. Emperador, M. Pi, and E. Lipparini
Density-functional calculations of magnetoplasmons in quantum rings 15 301
A. Emperador, M. Barranco, E. Lipparini, M. Pi, and Ll. Serra
Electron localization and anisotropic magnetoconductivity in GaAs-AlAs superlattices 15 308
A. B. Gougam, J. Sicart, J. L. Robert, and B. Etienne
Electron-optical phonon interaction and in-plane mobility in lead chalcogenide quantum-well structures 15 312
Victor Bondarenko
Universal structure of the edge states of the fractional quantum Hall states 15 323
Ana Lopez and Eduardo Fradkin
Monte Carlo dynamics below the Au-GaAs interface for ballistic-electron-emission microscopy 15 332
E. Y. Lee
Local-density approximation study of semiconductor/metal adsorption characteristics: Ge/Ag(100) 15 337
S. Sawaya, J. Goniakowski, and G. Tréglia
Exciton diffusion and dissociation in conjugated polymer/fullerene blends and heterostructures 15 346
A. Haugeneder, M. Neges, C. Kallinger, W. Spirkl, U. Lemmer, J. Feldmann, U. Scherf, E. Harth, A. Gügel, and K. Müllen
Conduction mechanism of hydrogenated nanocrystalline silicon films 15 352
Y. L. He, G. Y. Hu, M. B. Yu, M. Liu, J. L. Wang, and G. Y. Xu
Dynamic process of anti-Stokes photoluminescence at a long-range-ordered $Ga_{0.5}In_{0.5}P/GaAs$ heterointerface 15 358
Takashi Kita, Taneo Nishino, C. Geng, F. Scholz, and H. Schweizer
Time-resolved photoluminescence as a probe of internal electric fields in GaN-(GaAl)N quantum wells 15 363
Pierre Lefebvre, Jacques Allègre, Bernard Gil, Henry Mathieu, Nicolas Grandjean, Mathieu Leroux, Jean Massies, and Pierre Bigenwald

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 59, NUMBER 23** **15 JUNE 1999-I**

Manipulating the energy levels of semiconductor quantum dots 15 368
S. Fafard, Z. R. Wasilewski, C. Ni. Allen, D. Picard, M. Spanner, J. P. McCaffrey, and P. G. Piva
Continuous-time random-walk model of electron transport in nanocrystalline TiO_2 electrodes 15 374
Jenny Nelson
Supercell approach to the optical properties of porous silicon 15 381
M. Cruz, M. R. Beltrán, C. Wang, J. Tagüeña-Martínez, and Yuri G. Rubo
Quantum interference and nonlinear optical processes in the conduction bands of infrared-coupled quantum wells 15 388
S. M. Sadeghi, S. R. Leffler, and J. Meyer
Optical study of $Al_{0.4}Ga_{0.6}Sb/GaSb$ single quantum wells 15 395
R. Ferrini, M. Geddo, G. Guizzetti, M. Patrini, S. Franchi, C. Bocchi, E. Kh. Mukhamedzhanov, A. Baraldi, and R. Magnanini
Anisotropy-induced optical transitions in PbSe and PbS spherical quantum dots 15 402
A. D. Andreev and A. A. Lipovskii
Localization-enhanced biexciton binding in semiconductors 15 405
W. Langbein and J. M. Hvam
Hyper-Raman scattering in semiconductors: A quantum optical process in the strong-coupling regime 15 409
Salvatore Savasta and Raffaello Girlanda
Electron-phonon interaction in mixed crystals 15 422
Ruisheng Zheng and Mitsuru Matsuura
Substrate for atomic chain electronics 15 430
Toshishige Yamada, Charles W. Bauschlicher, Jr., and Harry Partridge

Surface physics, low-dimensional systems, and related topics

Transformation of molecular oxygen on a platinum surface: A theoretical calculation of STM images 15 437
M.-L. Bocquet, J. Cerdà, and P. Sautet
Structure of Cu(115): Clean surface and its oxygen-induced facets 15 446
D. A. Walko and I. K. Robinson
First-principles study of potassium adsorption on TiO_2 surfaces 15 457
J. Muscat, N. M. Harrison, and G. Thornton
Synchrotron x-ray-diffraction study of the structure and growth of Xe films adsorbed on the Ag(111) surface 15 464
Pengcheng Dai, Z. Wu, T. Angot, S.-K. Wang, H. Taub, and S. N. Ehrlich
Vibrational electron spectroscopy of molecules in solids: Effect of the conduction-band density of states 15 480
M. Michaud, M. Lepage, and L. Sanche
Influence of adsorbates, crystal structure, and target temperature on the sputtering yield and kinetic-energy distribution of excited Ni atoms 15 495
A. Cortona, W. Husinsky, and G. Betz
Proton-induced kinetic plasmon excitation in Al and Mg 15 506
S. M. Ritzau, R. A. Baragiola, and R. C. Monreal
Synthesis and characterization of Si/Cs/O nanocluster thin films with negative electron affinity 15 513
L. N. Dinh, W. McLean II, M. A. Schildbach, and M. Balooch
Pyramid growth without deposition noise 15 523
D. C. Vernon, M. Siegert, and M. Plischke
Electronic states of charge-ordering $Nd_{0.5}Sr_{0.5}MnO_3$ probed by photoemission 15 528
A. Sekiyama, S. Suga, M. Fujikawa, S. Imada, T. Iwasaki, K. Matsuda, T. Matsushita, K. V. Kaznacheyev, A. Fujimori, H. Kuwahara, and Y. Tokura
Structural and electronic properties of chemisorbed oxygen on Rh(111) 15 533
M. V. Ganduglia-Pirovano and M. Scheffler

Cumulative Author Index 15 544